

Mingqiang Huang

List of Publications by Year in descending order

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Version: 2024-02-01

16
papers

1,035
citations

840119

11
h-index

1058022

14
g-index

17
all docs

17
docs citations

17
times ranked

1889
citing authors

#	ARTICLE	IF	CITATIONS
1	Broadband Black Phosphorus Photodetectors with High Responsivity. <i>Advanced Materials</i> , 2016, 28, 3481-3485.	11.1	364
2	Multifunctional high-performance van der Waals heterostructures. <i>Nature Nanotechnology</i> , 2017, 12, 1148-1154.	15.6	278
3	Performance Potential and Limit of MoS ₂ Transistors. <i>Advanced Materials</i> , 2015, 27, 1547-1552.	11.1	92
4	A transverse tunnelling field-effect transistor made from a van der Waals heterostructure. <i>Nature Electronics</i> , 2020, 3, 106-112.	13.1	69
5	Flexible electronic synapse enabled by ferroelectric field effect transistor for robust neuromorphic computing. <i>Applied Physics Letters</i> , 2020, 117, .	1.5	57
6	Design and Implementation of Ternary Logic Integrated Circuits by Using Novel Two-Dimensional Materials. <i>Applied Sciences (Switzerland)</i> , 2019, 9, 4212.	1.3	33
7	High Performance Black Phosphorus Electronic and Photonic Devices with HfLaO Dielectric. <i>IEEE Electron Device Letters</i> , 2018, 39, 127-130.	2.2	31
8	High field transport of high performance black phosphorus transistors. <i>Applied Physics Letters</i> , 2017, 110, .	1.5	27
9	Optimized Transport Properties in Lithium Doped Black Phosphorus Transistors. <i>IEEE Electron Device Letters</i> , 2018, 39, 769-772.	2.2	25
10	Hardware-Friendly Stochastic and Adaptive Learning in Memristor Convolutional Neural Networks. <i>Advanced Intelligent Systems</i> , 2021, 3, 2100041.	3.3	16
11	Black Phosphorus Radio Frequency Electronics at Cryogenic Temperatures. <i>Advanced Electronic Materials</i> , 2018, 4, 1800138.	2.6	15
12	Global-Gate Controlled One-Transistor One-Digital-Memristor Structure for Low-Bit Neural Network. <i>IEEE Electron Device Letters</i> , 2021, 42, 106-109.	2.2	9
13	Performance Optimization of Atomic Layer Deposited HfO _x Memristor by Annealing With Back-End-of-Line Compatibility. <i>IEEE Electron Device Letters</i> , 2022, 43, 1141-1144.	2.2	9
14	A High Performance Multi-Bit-Width Booth Vector Systolic Accelerator for NAS Optimized Deep Learning Neural Networks. <i>IEEE Transactions on Circuits and Systems I: Regular Papers</i> , 2022, 69, 3619-3631.	3.5	8
15	High-performance two-dimensional transistors and circuits. , 2018, , .		2
16	High performance transistors based on two dimensional materials. , 2017, , .		0